Charge Ordered Insulator without Magnetic Order Studied by Correlator
Projection Method

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The Hubbard model with additional intersite interaction V' (the extended Hubbard model) is investigated by the correlator projection method (CPM). CPM is a newly developed numerical method which combines the equation-of motion approach and the dynamical mean-eld theory. Using this method, properties of the extended Hubbard Model at quarter lling are discussed with special emphasis on the metal-insulator transition induced by electron-electron correlations. The result shows a metal-insulator transition to a charge ordered insulator with antiferrom agnetic order at low temperatures, but a charge ordered insulator without magnetic symmetry breaking at intermediate temperatures. Here, the magnetic order is found to be suppressed to low temperatures because of the smallness of the exchange coupling  $J_{\rm e}$ . The present results are in sharp contrast with the Hatree-Fock approximation whereas in agreement with the experimental results on quarter-lled materials with strong correlations, such as organic conductors.

KEYW ORDS: extended Hubbard model, metal-insulator transition, intersite Coulomb interaction

#### 1. Introduction

Translational sym m etry breaking in the charge degrees of freedom, or charge ordering, is widely observed in strongly correlated electron systems such as manganites,  $^{1(3)}$  vanadates, and various organic conductors. In these systems, the charge-ordering transition offen accompany a large jump in electric resistivity or metal-insulator transition (MIT). Thas attracted much interest both from theoretical and experimental point of views. Charge ordering is indeed one of the fundamental routes to cause metal-insulator transitions in non-integer lling systems. The nature of this transition, however, is not well understood yet. Here, we refer to non-integer lling as the state where the electron number per site is not an integer. The insulating phase of these systems usually have translational symmetry breaking in the charge degrees of freedom. This is in marked contrast to the case of integer-lling systems, which have integer numbers of electron (s) per site. Insulating phase in the latter systems, such as the Mott insulator phase, usually has no symmetry breaking in the charge

degrees of freedom. Here in this paper, we focus on systems at simple rational llings that stabilize commensurate charge orders. We also focus on the interplay of the on-site and intersite Coulomb interactions in such charge-ordering transitions.

There are several properties in charge-ordering transitions that require theoretical clarications:

- 1) The system can become insulating with charge order but without the magnetic order: This is expected if one considers the strong-coupling limit. Systems with repulsive interaction at commensurate lling in this limit takes the lowest energy when the charge forms a certain spatial pattern to reduce the Coulomb interaction energy. In such phases, any excitations in the charge degrees of freedom has a nite gap. The system is then an insulator irrespective of the magnetic ordering, which may not be formed due to the quantum and/or thermal uctuations. This expectation remains to be clarified except that limit. Experimentally, non-magnetic insulating phase is indeed observed at intermediate temperatures in wide range of real materials.  $^{5,6}$
- 2) Many systems undergo metal-insulator transitions simultaneously at the point where the long-ranged charge order is formed i.e. no intermediate phase with charge order and metallic conductivity appears: Here, we do not in principle exclude the possibility of the charge-ordered metallic state. However, the above-mentioned feature is experimentally observed in most of the real charge-ordering materials. 3(5,12(14))

On the other hand, using simple theoretical methods such as the mean-eld approximation, one easily obtain charge-ordered metallic phase in a wide region of the parameter space as we discuss below. Mean-eld approximations fail in reproducing the general tendency in realistic parameter region.

Studies on metal-insulator transition induced by the strong electron-electron correlations require careful treatment of the two intriguing aspects of quantum mechanics, itineracy and locality. This is one of the most fundamental problems in condensed matter physics. In integer—lling systems, such transition is called the Mott transition 15) and has been the subject of intensive research. These studies were based on a lattice model with only the on-site electron repulsion, called the Hubbard model. The Hubbard model is dened as

$$H = \begin{cases} X & X \\ t_{i;j}c_{i}^{y}c_{j} + U & n_{i}n_{i\#}: \\ t_{i;j;} & t_{i} \end{cases}$$
 (1)

Here,  $c_i$  ( $c_i^Y$ ) is the annihilation (creation) operator of an electron at an atom ic site i with a spin index. The number operator on site i with spin is represented by  $n_i$ , while  $t_{i;j}$  is an electron transfer from an atom ic site i to j, and U is the local C oulom D repulsion. Recent development of numerical calculations has allowed detailed analyses on the D ott transition. The dynamical mean-eld theory D and its extension have also applied to clarify nite-temperature properties of the D ott transition.

On the other hand, as for metal-insulator transitions in non-integer—lling systems, theoretical mehods are still not well established. In this paper, we will study on the methods to treat those transitions induced by the charge ordering.

Charge ordering in a broad sense includes the W igner crystallization. The charge ordering in strongly correlated systems, however, is much dierent from the W igner crystallization of the electron gas in the continuum space: First, there is a periodic potential formed by the positively (or negatively, if carriers are holes) charged ions, which may allow the ordering at relatively higher carrier concentrations. Second, as a consequence of the rst, the ordering occurs mostly at commensurate llings and easily melts away from it. The importance of commensurability has been pointed out in ref. In this paper, we call only this commensurate case as the charge order. In order to obtain a model for this charge order, we assume that the long-ranged part of the Coulomb potential is screened by the large carrier concentration. We denote the simplified model, the extended Hubbard model as

Here,  $V_{i;j}$  is the o-site Coulomb interaction. Other notation is the same as eq.(1). For simplicity, we restrict the range of V to only the nearest neighbor sites. We consider square lattice and hopping integral  $t_{i;j}$  takes the value the formuly the nearest neighbor pair (i;j) and zero otherwise.

Charge ordering has been studied by several theoretical methods using the extended Hubbard model de ned in eq. (2). Here, we will exam ine some of the existing theoretical methods. The Hartree-Fock approximation (HFA) is the most standard method to treat the charge ordering problem s. 10 Using HFA, one can reproduce charge-ordered phase. On the other hand, HFA cannot reproduce the charge-ordered insulating phase without magnetic ordering. HFA also overestimates the ordered phases. The drawbacks arise from the neglect of dynamical and spatial correlation elects. Perturbative approaches may be powerful tool for analyzing metallic phase of these systems. However, most of them cannot describe insulating or symmetry-broken phases. The dynamical mean—eld theory (DMFT) can also be applied with appropriate mapping to the inhite dimensional model. It, however, fails in reproducing the insulating phase in the absence of the magnetic order. This is asscribed to the fact that it treats the intersite interactions only in the static mean—eld level. Exact diagonalization (ED) can also be a standard approach to this problem. There is, however, nite size elect that becomes severe in determining metal-insulator transitions and/or charge ordering transitions. It is also dicult to obtain nite-temperature properties.

Above considerations im pose the requirements for an improved theoretical approach; (1) a non-perturbative method to describe the insulating and/or charge-ordered phases, (2) an analytic method that can describe the nite-temperature phases, (3) a method which can

equally treat both intersite and onsite interactions to realize insulating phases.

In this paper, we analyze the charge-ordering phenom enaby using the correlator projection method (CPM). We show that it succeeds in reproducing the presence of the insulating charge-ordered phase in the absence of the magnetic order.

The form ulation of the correlator projection method is given in Sec 2. Here, we sum marize the properties of this method. CPM is a new by developed method that combines the equation-of motion approach and the dynamical mean-eld theory. It can treat the correlation extracts beyond the mean-eld level in a self-consistent manner. It is also a non-perturbative method that can describe the symmetry broken state and/or the insulating state. It consists of two parts: First, one derives the analytic form of the Green's function by the equation-of motion approach. Second, one calculates the self-energy part by extending the dynamical mean-eld theory in order to restore the uctuation extracts. These two parts are performed in a self-consistent manner on the basis of the operator projection theory and the dynamical mean-eld theory.

The dynam ical mean-eld theory is suited for treating the elects of dynam ical quantum uctuations. However, it may not be adequate to treat that of spatial uctuations. CPM allows to overcome this drawback by taking account of spatial uctuations. We concentrate on the system at commensurate lling in strong coupling regime, where the elect of spatial uctuation is relatively small.

The results obtained by the present approach are given in Sec.3.CPM have reproduced charge-ordered insulating phase without order in the spin-degree of freedom.

The result is in agreement with several experimental observations. Comparisons to real materials are given in Sec.4.

Sec.5 is devoted to the sum mary of this paper.

# 2. Form ulation

## 2.1 Correlator Projection Method

As we have m entioned in the introduction, the correlator projection m ethod (CPM) combines two procedures.

The rst procedure is based on the equation-ofm otion decoupling approach originally named the operator projection method (OPM). This approach, which was originally developed for analyses of stochastic phenomena, was rst applied to the Hubbard model by Roth. She solved the equation of motion up to the second order and obtained a Green's function with two poles. This approximation is called the two-pole approximation (TPA). TPA has been further applied for the Hubbard model and some other models with strong electron-electron correlations. The same of the Hubbard model and some other models with strong electron-electron correlations.

Equation-of-motion approaches are suited for strongly correlated electron systems since one can treat the local constraint (the Pauli principle) correctly and can distinguish between

the double occupancy and single occupancy. Thus one can treat the strong on-site and o -site C oulomb interaction. The obtained G reen's function correctly reproduces the high-energy part of physics. On the other hand, however, they tend to fail in describing the low-energy part of physics since they decouple the higher-order operators, which describe low-energy collective motions.

The correlator projection method overcomes this drawback by introducing a rened self-energy at the point one truncates the equation of motion. When one solves the equation of motion for the Green's function, it leaves the self-energy as an unknown quantity. The equation of motion for the self-energy (, which we call the rst-order self-energy (1) from now on) is then given and leaves the second-order self-energy (2) as an unknown object. This sequence of continued fraction expansion continues. Using OPM, one can obtain the explicit form of the self-energy, which we call the higher-order self-energy', (n). The second procedure of CPM is to evaluate the highest-order self-energy, say (n), in self-consistent manner by extending the dynamical mean-eld theory. The continued fraction is truncated at (n). Then, (n) is self-consistently determined by assuming that (n) is momentum independent. This reduces to the original dynamical mean-eld theory when one takes n = 1. By solving a higher-order self-energy self-consistently, it system atically incorporates the spatial uctuations with increasing n. For practical use, even n = 2 gives a signicant in provement, where (1) recovers momentum dependence.

The rst attempt of applying this method was given in the half-led Hubbard model with the second-neighbor hopping  $t^{0.21}$ . It reproduced the metal-insulator transition at the parameters in good agreement with a reliable numerical calculation.  $t^{17}$ 

### 2.2 Formulation of CPM

Now, we sum marize the concrete formulation of CPM . 21)

## 2.2.1 The rst procedure; OPM

One starts with a set of operators f  $_{\rm i}$ g for physical quantities. The equation of motion for the operators is expressed as

$$\frac{\theta_{\dot{a}}}{\theta} = \dot{\uparrow}_{\dot{a}} : \tag{3}$$

Through the remaining part of this paper, we take imaginary time representation; ()  $e^{H}$   $e^{H}$  with the Hamiltonian of the system H. Here, we introduced operator !, which is dened from !A A;H] for any operator A. The right hand side of eq. (3) is expressed as

$$\uparrow_{i} = X \qquad (1;1) \\
\downarrow_{j} \qquad (4)$$

The rst term of the right hand side of eq. (4) is regarded as \system part", but in practice describes the part within the subspace of  $f_{ig}$ . Its coe cient is represented as  $f_{ig}$ .

explicit form is given later in eq. (5). The second term of eq.(4) describes the \environment part" which in fact describes the part orthogonal to the operator set f ig. The decomposition into the two parts in eq. (4) is explicitly obtained by projection. We denote the projection operator to the subspace of the operator set f ig as  $\hat{P_1}$ . It is denoted for Fermionic/Bosonic operators as

$$\hat{P_1}X$$
  $fX; ig$  hf;  $fX : ig$   $fX : ig$   $fX : ig$ 

Here, is the vector notation of f ig whose i'th element is i. Then the system part is explicitly obtained from

$$\begin{array}{ccc}
X & & & \\
& & & \\
& & & \\
& & & \\
\downarrow & & \\
\downarrow$$

The next step is to derive the equation of motion for i;

$$\frac{0}{0} = 1 \cdot \frac{(2)}{1} = 1$$

By applying another projection operator, the right hand side becomes

$$\uparrow_{i}^{(2)} = X \qquad (2;1) \\ ij \qquad j + (2;2) \quad (2) \\ ij \qquad j + ij \qquad j + i \qquad (7)$$

The higher order equations of motion  $: _{i}^{(n)} = _{l=1}^{P} _{j \ ij}^{P} _{j \ ij}^{(n;l)} (l) + _{n+1}^{(n+1)}$  are obtained similarly with the matrices dened as

$$\begin{array}{ccc}
X & & & & \text{(n;i)} & \text{(l)} & = & \hat{P}_1(\hat{T} & & \text{(n)}); \\
& & & & & & & & & & \\
j & & & & & & & & \\
\end{array}$$
(8)

Here, the n-th order operators are de ned as

$$\hat{P}_{n}X$$
 fX;  $\hat{P}_{n}Y_{g}$  (hf  $\hat{P}_{n}Y_{g}$  i)  $\hat{P}_{n}Y_{g}$  i)  $\hat{P}_{n}Y_{g}$  i) (9)

$$(n+1)$$
  $Y^n$   $(1 P_1) : (n)$ : (10)

These equations generate (imaginary) frequency-dependent correlation functions. We introduce the notation hh  $_{i!\,n}$  his the Fourier transformation of the correlation function

hx; 
$$Y^{y}ii_{i!_{n}}$$
 d  $e^{i!_{n}}$  h X ( ) $Y^{y}i:$ 

W e also introduce the Fourier transform ation of the operators f  $\,_{\mathrm{i}}$ g as

$$r = \frac{1}{N} X$$
  $ie^{ikr_i}$ ;

as well as the Fourier transform ation of m atrices A  $_{\rm ij}$  as

$$A_{k} = \frac{1}{N} X X A_{ij} e^{ik(r_{i} r_{j})};$$

where N is the number of sites in the system, and ri is the coordinate of the i's site. The

equation of motion for the correlation function becomes

and thus the G reen's function becomes

The self-energy (n) is given as

$$_{k}^{(n)} = hh_{k}^{(n+1)};_{k}^{(n+1)y}ii_{i!n}$$
:

If one stops the expansion at the  $\,$  rst step, and neglects  $\,$   $^{(1)}$ , it obviously reproduces the Hartree-Fock Approximation (HFA). If one stops at the second step, and neglects (2), it gives the two-pole approximation (TPA). 30 In case of the Hubbard model, for example, one can obtain the upper and lower Hubbard band at this step. Here, in the CPM, we calculate (2) to reach a better approximation.

## 2.2.2 The second procedure; DMFT

By means of OPM in the previous section, we obtain the Green's function of the system as

$$G_{k}(i!_{n}) = \frac{1}{i!_{n} \binom{(1;1)}{k} \binom{(2;1)}{i!_{n} \binom{(2;2)}{k} \binom{(2)}{k} (i!_{n})}} : (13)$$

In order to formulate the local approximation scheme, we reformulate the equation of motion in the previous section by the path integral. In the following equations, we introduce the G rassmann eld  $^{(n)}(^{(n)})$  corresponding to the (normalized) operators  $^{(n)}=^{p}$   $\frac{p}{(n,m-1)}$  $(\hat{\ }^{(n)}y=\frac{p}{(n\,m^{-1})})$  . The partition function is given by Z=p Z=p  $D_{i}(\ )p_{i}(\ )e^{S};$ 

$$Z = D_{i}()D_{i}()e^{S};$$
(14)

where the action has the form

Here, the elective action is derived so that its functional derivative makes correct equation of motion for and (2). If one could solve the action for (2) exactly, one would obtain  $G^{(1)}$ , where  $G^{(1)}$  is the full propagator for the  $G^{(2)}$  eld. By using  $G^{(1)}$ , eq.(15) is rewritten as

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In general, however, one cannot rigorously solve the action for (2) elds. Here, we introduce local but im aginary-time dependent Weiss eld G (1) to approximate the action for the elds without the last two terms in eq. (15). Then, using  $G^{(1)}$ , the action is rewritten as

Here, the W eiss  $eld' G^{(0)}$  is given as

$$G_{ij}^{(0)}$$
 (  $C_{ij}^{(0)}$  )

With the Weiss eld, we can now solve (2). As was shown in the last section, (2) has the form

$$^{(2)} = h ^{(3)}; ^{(3)y} ii_{i!n};$$
 (20)

where the eld  $^{(3)}$  can be expressed with the original eld. Since we have the W eiss eld eld, we can solve the 'second-order self-energy' in eq.(20) with some proper method. In this paper, we adopt the iterative perturbation theory (IPT) as we discuss below.

The whole iteration procedure is explicitly given below:

[1] IPT solution to

Evaluate the self-energy (2) as

The operator  $\ ^{(3)}$  is evaluated by W ick expansion. For  $\ ^{(3)}$  expressed in the form  $\frac{1}{N^{2}} \stackrel{P}{\stackrel{k^{0}}{=}} k^{0} ; q \stackrel{Y}{k^{0}} ; q \stackrel{Y}{k^{0}} + q \stackrel{k^{0}}{k} \stackrel{q}{\cdot} ; w \, e \, can \, \, expand \quad \ ^{(2)} \, \, by \, \, \mathbb{P} \, T \, \, as$ 

$$(2) = \frac{1}{N^3} \frac{X}{(2;1)} \frac{1}{k;k^0;q} G_{k^0}^{(0)} ( ) G_{k^0+q}^{(0)} ( ) G_{k}^{(0)} q^{()} :$$
 (22)

For the initial condition in the rst iteration, one may use the Green's function for the free particle for G (0).

[2] self-consistency equation

The local self-consistency condition is given as

$$G_{loc}^{(1)}(i!_n) = \frac{1}{N} \frac{X}{i!_n} \frac{1}{k^{(2;2)}} (2!_n)$$
(23)

[3] Dyson equation for G (1)

The Dyson equation for the eld (2) is given as

$$G^{(1)} \stackrel{1}{=} (i!_n) = G_{loc} \stackrel{(1)}{=} i!_n) + \stackrel{(2)}{=} (i!_n)$$
: (24)

[4] Equation for W eiss  $eld'G_k$ 

From the eq.(19), we can calculate the momentum dependent W eiss eld for the eld  $_{\rm k}$  as

$$G_{k}^{(0)} \stackrel{1}{=} i!_{n} \stackrel{(1;1)}{=} k \stackrel{q}{=} \frac{q}{(2;1)} \stackrel{q}{=} (i!_{n}) \stackrel{(2;1)}{=} i!_{n}$$
 (25)

A fter Fourier transform from  $G_k^{(0)}$  (i! n) to  $G_k^{(0)}$  ( ),  $G_k^{(0)}$  ( ) is substituted to eq.(22) and we repeat the procedure from [1]. The procedure [1]-[4] constitutes the iteration loop. The procedure is repeated until we reach the convergence. A fter the convergence, the G reen function is obtained as

$$G_{k}(i!_{n}) = \frac{1}{i!_{n} \binom{(1;1)}{k} \frac{k}{i!_{n} \binom{(2;2)}{k} \binom{(2)}{k} \binom{(2)}{k} \binom{(2)}{k}}} : (26)$$

## 2.3 Application to the extended Hubbard Model

We now apply this method to the extended Hubbard model de ned by eq.(2). Here, we introduce two methods in analyzing the model.

# 2.3.1 Standard approach

We rst apply the OPM procedure in a straightforward manner. Now we take  $c_i$  as the rst set of the operators  $_i$  in eq. (3).

The equation of motion eq. (3) reads,

The matrix element is given as

$$_{ij}^{(1;1)} = t_{ij} + h_{i} i_{i;j} X_{ij};$$

where  $_{i}$  = U  $n_{i}$  +  $_{j}^{P}$ V<sub>i;j</sub> $n_{j}$  and X  $_{i;j}$  = V<sub>ij</sub> $h_{j;i}$ ; i are direct and exchange elds with the notation  $_{i;j}$ ;  $_{i}^{Q}$  c<sub>j</sub>,  $_{i}$  n<sub>i</sub> +  $_{i}$  +  $_{i}$  W e also de ne the following notations;  $_{i}$  =  $_{i}$  h  $_{i}$  i,  $_{i}$  =  $_{j}^{V}$ V<sub>ij</sub> $n_{j}$ :  $_{i}$  =  $_{i}^{V}$  h  $_{i}^{V}$  i: The second operator  $_{i}$  is obtained as  $_{i}$  =  $_{i}$  c $_{i}$  + V<sub>i;j</sub> $h_{i;j}$ ; ic $_{j}$ :

We can now proceed to the equation of motion for the second set of operators, which is

form ally written as

where the matrices are written as follows;

Here,  $S_i$  is the spin operator on the site i, de ned as  $S_i = \frac{1}{2}c_i^y$ ,  $c_j$  with Pauli matrices . The singlet pair operator on the site i, i is de ned as i  $g_{i}c_{i\#}$ . The motion of the interacting charges is rejected in . The term with i comes from the interaction part. It divers from hibecause of the Pauli principle. (e.g.  $n_i$   $n_i$ 

The remaining operator, (the third operator of the right hand side of the eq. (28)) R rejects the uctuation of . It is given as

Here,  $R_i^0$  contains higher order operators as

$$R_{i}^{0} = Q_{i} C_{i}$$

with  $Q_i$  de ned as  $Q_i$  (  $_i$ ) )  $^2$   $\frac{h(_i)^3i}{h(_i)^2i}$   $_i$ : The correlation functions of this operator give a convolution of G reen's function with charge/spin correlation functions of more than three terms such as hh  $n_i$   $n_j$   $n_l$ ii in which indices i, j and lare all dierent. A ssuming that these higher order uctuations are small, we neglect this operator  $R_i^0$ .

Here, in the matrix elements, one nds equal-time correlation functions like  $h(\ )^2i$  that cannot be uniquely determined by the single-particle Green's function. There are several ways to determine these correlation functions.

(1) The second-order perturbation theory: One way is to make use of one of various perturbative methods. Among them, we adopt the second order perturbation theory. Here, we do not start from the free-particle Green function, but use obtained (renormalized) Green function and take up to the second order diagrams to include correlation elects. Although it is one of the simplest approximations, it is favorable for our purpose here since it conserves the local summation rule; 33)

$$\frac{1}{N} \sum_{\substack{!_n = q}}^{X} X X {q!_n} (i!_n) + q^{(sp)} (i!_n) = hni(2 hni);$$
 (30)

Here,  $q^{(ch)}(i!_n)$   $hhq_i$ ,  $n_{qii_{i!_n}}$  and  $q^{(sp)}(i!_n)$   $hh(n_{qi}, n_{qi})$ ;  $(n_{qi}, n_{qi})$ ;  $(n_{qi}, n_{qi})$  are the charge and spin correlation functions, respectively. By the second order perturbation theory, they are derived as

$$\frac{\text{(ch)}}{q}(i!_n) = 2f \frac{0}{q}(i!_n) + \frac{0}{q}(i!_n)(U + 2V_q) \frac{0}{q}(i!_n) 
\frac{1}{N^2} \sum_{k,k^0}^{N} \frac{0}{k_{qq}}(i!_n)V_{k_{q}} \frac{0}{k_{q}}(i!_n)g;$$
(31)

Here,  $_{q}^{0}(i!_{n})$  and  $_{k\neq q}^{0}(i!_{n})$  are zeroth order susceptibility functions de ned as

$${}_{q}^{0}(i!_{n}) = \frac{1}{N} {}_{i!_{n}} {}_{k} {}_{G_{k+q}}(i!_{1} + i!_{n})G_{k}(i!_{1})$$
(33)

$${}_{k,q}^{0}(i!_{n}) = \frac{1}{2} {}_{i!_{1}}^{X} G_{k+q}(i!_{1} + i!_{n})G_{k}(i!_{1});$$
(34)

where  $G_k$  (i.i., is determined from eq.(26). On the other hand, it may underestimate the local correlation e ects especially in the case of strong coupling.

(2) The exact diagonalization (ED) of small cluster: We can also take a completely dierent approach by simply replacing the correlation functions with the result of exact diagonalization (ED) of a small cluster. Adopting ED, one can take account of the strong local correlation e ects. Here we emphasize that we only need short-ranged equal time correlation functions that are not likely to severely suer from nite size e ects. In order to treat the symmetry-broken state in the ED calculation, we divide the lattice into two sublattices, A and B, and

apply small sym metry-breaking eld has follows;

Here, the rst term  $H_{EHM}$  is the original Ham iltonian of the extended Hubbard model given in eq. (2), while the second and third term indicate the symmetry breaking eld. The eld h is set h=0.001t. The shortcoming of this approach is that the correlation functions are determined independently of the lattice G reen's function, and are not fully self-consistent.

We adopt the former approach to derive the charge ordering transition where the consistency to the Green's function is particularly important. On the other hand, we adopt the latter approach to analyze the detailed properties for the charge-ordered phase.

## 2.3.2 Formulation based on the CDW basis

In order to further analyze the properties of the charge-ordered phase, we introduce a di erent approach using di erent basis representation. A lithough in principle, the operator projection theory does not depend on the choice of basis, in actual calculations, however, details of the results do depend on the chosen basis set due to the truncation of the operator expansion at a nite step. Because of the truncation, it is better to employ the basis function which is the eignfunction of the same symmetry as that of the correct phase. For example, in the charge-disordered state, the basis function of the free-particle H am iltonian gives faster convergence and gives better results at a xed level of the truncation. This is the case in the previous subsection, namely, the standard approach. On the other hand, if the system is in the charge ordered phase, the basis function of charge density wave (CDW) mean—eld solution is expected to give better results. Here, we introduce an approximate formulation which is valid under large polarization. The idea is to solve the equation of motion for the operators represented by the eignfunctions of the mean—eld H am iltonian for the charge order.

In the following equations, we consider the square lattice as an example. Hence, at quarter lling, two sublattices A and B are enough to discuss possible charge ordering. The dispersion in the two-dimensional square lattice is denoted as  $\frac{1}{2}$  ( $\cos(\frac{1}{2}) + \cos(\frac{1}{2})$ ), and electron density per site as  $\ln_A i$  and  $\ln_B i$ , for each sublattice. We also use the notation  $\ln i$   $\frac{1}{2}$  ( $\ln_A i + \ln_B i$ ) We take new basis as

$$a_k = u_k c_k^A + v_k c_k^B (35a)$$

$$b_k = v_k c_k^A + u_k c_k^B : (35b)$$

Here,  $c_k^R$  ( $c_k^{R\,Y}$ ) is the annihilation (creation) operator of the B loch state at sublattice R (R = A or B), with momentum k. Here, and in the following equations in this section, k refers to the wavevector inside the reduced B roullin zone (RBZ). We  $x u_k$  and  $v_k$  as the eigenvector of the mean-eld Ham iltonian matrix  $^{H\,F}$ . The Hubbard term U  $^P$   $_i n_i$  is treated in later

calculations. We de ne the CDW order parameter CDW as

$$_{\text{CDW}} = \frac{1}{2} \quad 4V \text{ (hn}_{\text{A}} i \quad \text{hn}_{\text{B}} i);$$
 (36)

The order parameter is to be determined in a self-consistent manner. The mean-eld Hamiltonian becomes

$${}^{\mathrm{HF}}_{k} = {}^{\mathrm{4V \, hni}} {}^{\mathrm{CDW}} {}^{\mathrm{t}_{k}} {}^{\mathrm{t}_{k}} : \qquad (37)$$

Hence  $u_k\,$  and  $v_k\,$  is obtained by the following equations:

Here,  $_{k}^{A}$  = 4V hni  $_{k}$  and  $_{k}^{B}$  = 4V hni+  $_{k}$  are eignvalues of the m ean-eld H am iltonian with

$$_{k} = \frac{q}{CDW} + t_{k}^{2}$$
: (39)

The eigenvectors are determined from

$$u_k = \frac{s - \frac{k + CDW}{2k}}{2k}; \tag{40a}$$

$$v_{k} = \frac{k \quad CDW}{2 \quad k}$$
 (40b)

We perform inverse Fourier-transformation of eq.(35) to obtain site representation as

$$a_{i} = \frac{1}{P} \frac{X}{N} a_{k} e^{i k r_{i}} i 2 A;$$
 (41a)

$$b_{j} = p \frac{1}{N} \sum_{k=1}^{N} b_{k} e^{i k r_{j}} j 2 B :$$
 (41b)

The last expression also satis es the anticom mutation relation;

$$fa_{i};a_{i0}^{y}g = i_{i};i^{0};$$
 (42a)

$$fb_{j};b_{j0}^{y}g = j_{jj0};$$
 (42b)

and any other pairs than these anticommute. Note that in spite of the site index, they have nonzero am plitudes over m any lattice sites as

$$a_{i} = \begin{pmatrix} X & X & X \\ u_{i;i} c_{i0}^{A} + & v_{i;j} c_{j}^{B}; \end{pmatrix}$$
 (43a)

$$a_{i} = \begin{cases} X & X \\ u_{i;i^{0}}c_{i^{0}}^{A} + X \\ X & V_{i;j}c_{j}^{B}; \end{cases}$$

$$b_{j} = \begin{cases} x & X \\ V_{j;i}c_{i}^{A} + X \\ v_{j;j^{0}}c_{j^{0}}^{B}; \end{cases}$$

$$(43a)$$

where  $u_{i;j} = u(r_i r_j)$  and  $v_{i;j} = v(r_i r_j)$  indicate the Fourier transform ation of  $u_k$ and  $v_k$ . The Ham iltonian can be written with the new operators. We introduce the following

notations;

$$s_{i;x} = \begin{pmatrix} u_{i;x} & x & 2 & A; \\ v_{i;x} & x & 2 & B; \\ v_{j;x} & x & 2 & B; \\ q_{j;x} = \begin{pmatrix} v_{j;x} & x & 2 & A; \\ u_{j;x} & x & 2 & B; \\ \end{pmatrix}$$

$$c_{x;} = \begin{pmatrix} a_{x;} & x & 2 & A; \\ b_{x;} & x & 2 & B; \\ \end{pmatrix}$$

Wewrite the Hamiltonian as

$$H = H_{mf} + H_{U} + H^{0}$$
: (44)

Here, H  $_{\text{m f}}$  is the mean-eld term s;

and H U is the Hubbard interaction term s;

$$H_{U} = X \qquad X \qquad X \qquad X \qquad X \qquad U n_{j"}^{A} n_{j\#}^{A} + X \qquad U n_{j"}^{B} n_{j\#}^{B}; \qquad (46)$$

The rest part of the mean eld Hamiltonian is given by

$$H^{0} = \begin{array}{c} X \\ V_{i,j} & n_{i}^{A} & n_{j}^{B} : \end{array}$$
 (47)

Then, H  $_{\rm m\ f}$  is rewritten as

$$H_{mf} = X X X B_{i,i0} a_i^y a_{i0} + X B_{j,j0} b_j^y b_{j0} + E_{mf};$$

$$i:i^{0} 2 A i,j^{0} 2 B$$
(48)

Here,  $_{\rm in}^{\rm A}$  and  $_{\rm jm}^{\rm B}$  is the Fourier transform of  $_{\rm k}^{\rm A}$  and  $_{\rm k}^{\rm B}$  within each sublattice, respectively, and  $E_{mf}$  is the mean eld energy;

$$E_{mf}$$
 2V hn  $iN_e + \frac{2}{CDW}N$ ;

with N  $_{
m e}$  being the total electron number. Whereas H  $^{
m 0}$  and H  $_{
m U}$  are written by substituting

$$n_{i} = S_{i,x}S_{i,y}d_{x}^{y}d_{y}$$
 (49a)

$$n_{i} = \begin{cases} x \\ s_{i,x} s_{i,y} d_{x}^{y} d_{y} \end{cases}$$

$$n_{j} = \begin{cases} x \\ y \\ q_{j,x} q_{j,y} d_{x}^{y} d_{y} \end{cases}$$

$$(49a)$$

$$(49b)$$

into the original number operators  $n_x^R$  in eqs. (46),(47).

In general case, the above-m entioned procedure yields complication. However, it becomes simple in the largely disproportionated case. In the following of this section, we consider such case. We assume the CDW order parameter CDW to be considerably large so that we de ne

an expansion parameter p as

$$p = \frac{t}{2 c_{DW}}; \qquad (50)$$

Then  $u_k$  and  $v_k$  in eq.(40) are expanded in power of p up to  $\mbox{\ensuremath{p^2}}$  as

$$u_k = 1 \frac{t_k^2}{4 \frac{2}{CDW}} + O(p^4)$$
 (51a)

$$v_k = \frac{t_k}{2_{CDW}} + O(p^3)$$
: (51b)

Up to this order, their transform ations to the real-space representation have nonzero values only within the nearest neighbor sites. We introduce the notation  $p_{\rm ij}$  as

Then u and v become

$$u_{i;i^0} = u_{i;i^0} + O(p^2);$$
 (52a)

$$v_{i;j} = p_{i;j} + O(p^3)$$
: (52b)

In the above equation, i and  $i^0$  are on the same sublattice, whereas j is on the other. The original operators  $c_i^{\mathtt{A}}$  and  $c_j^{\mathtt{B}}$  are expressed by  $\mathtt{a}_i$  and  $\mathtt{b}_j$  as

$$c_i^{A} = f(a_i \qquad p_{i;j}b_j); \qquad (53a)$$

$$c_{i}^{A} = f(a_{i} \quad p_{i;j}b_{j});$$
 (53a)  
 $c_{j}^{B} = f( p_{j;i}a_{i} + b_{j});$  (53b)

with f being the normalization factor  $f = p \frac{1}{1 + 4p^2}$ . The number operators are rewritten as

$$n_{i}^{A} = f^{2}(a_{i}^{a} p_{i;j}(a_{i}^{y} b_{j} + b_{j}^{y} a_{i}));$$
 (54a)

$$n_{i}^{A} = f^{2}(_{i}^{a} p_{i,j}(a_{i}^{Y} b_{j} + b_{j}^{Y} a_{i}));$$

$$n_{j}^{B} = f^{2}(_{j}^{b} + p_{i,j}^{Y}(a_{i}^{Y} b_{j} + b_{j}^{Y} a_{i}));$$

$$(54a)$$

 $a_1^{y}$   $a_1$  , and  $b_1^{y}$   $b_2^{y}$   $b_3$  . At this point it is clear that the factor f can be absorbed U  $f^4$  and  $\nabla$  V  $f^4$ . The Hubbard interaction in the interaction parameter U and V as U term contains b -site' terms that describe the interaction with states centered at di erent sites.

We write down the kinetic equation for the operator a; up to the rst order of p as

with the "second" operator  $f_{\rm i}$  , de ned as

$$X$$

$$f_{i} \quad {}_{i} a_{i} \quad p_{ij} ( \quad {}_{i} \quad {}_{j} ) b_{j} :$$

$$(56)$$

Here, we have introduced the notation i, de ned as i i  $^P_j V_{ij} h n_j i$ : 0 ther notations are the same as in the previous subsection. In the derivation of eq. (55), we have used the fact that term swhich are o -diagonal in a' and b' bands such as  $ha_i^y$   $b_j i$  are of order p or higher, and term s like  $pha_i^y$   $b_j i$  can be neglected when we consider the order up to 0 (p). The equation for the elds  $b_j$  's is also obtained in the same way.

with the corresponding \second" operator  $g_i$  ,

$$g_{j}$$
  $j_{j}$   $b_{j}$   $p_{ji}(i_{j}, j_{j})a_{i}$ : (58)

The equation of m otion for the eld  $f_i$  becomes

The equation for  $g_i$  is also written in the same way;

The explicit forms of the remaining operators  $L_i$  and  $R_j$  will be given later. The matrix  $^{(1;1)}$  is dened as

$$_{\text{in}}^{(\text{aa}) (1;1)} = \text{UTh}^{a} \, i_{\text{in}} + {}^{\text{A}}_{\text{in}};$$
 (61)

$$_{ij}^{(ab) (1;1)} = p_{j} (\nabla h_{i}^{a} i \nabla h_{j}^{b} i);$$
 (62)

whereas  $^{\text{(bb)}\,(1;1)}$  is obtained from  $^{\text{(aa)}\,(1;1)}$  by replacing 'a (A)' with 'b(B)' and pwith p. Here,  $^{\text{(ba)}\,(1;1)}$  is obtained from the symmetry property  $^{\text{(ba)}\,(1;1)}_{ji} = ^{\text{(ab)}\,(1;1)}_{ij}$ . The matrix  $^{\text{(2;1)}}$  is also derived up to the rst order of p as

$$_{\text{in}}^{(\text{aa})(2;1)} = \text{h}()^2 i_{\text{in}};$$
 (63a)

$$_{ij}^{(ab)(2;1)} = hp_{ij}((_{i})^{2} (_{j})^{2})i;$$
 (63b)

Here, however, the matrix  $^{(2;1)}$  need to have positive eignvalue since it is the norm of the operators  $f_i$  and  $g_j$ . We modify it within the second order of p to guarantee the positivity. It is modified, in the momentum representation, as

$${}_{k}^{(2;1)} = \frac{1}{1 + (p_{k}^{2})} \qquad {}_{p_{k}} \qquad {}_{h} \qquad {}_{h} \qquad {}_{h} \qquad {}_{i} \qquad {}_{j}^{2} = \frac{1}{1 + (p_{k}^{2})} \qquad {}_{p_{k}} \qquad {}_{h} \qquad {}_{h$$

where  $p_k$  is the Fourier transform ation of  $p_{ij}$ . Since the right hand side of eq.(64) is a unitary

transform ation of a diagonal matrix with positive matrix elements,  $^{(2;1)}$  in this form has non-negative eignvalue. Note that eq.(64) is equivalent to the previous eq.(63) up to the rst order of p. In order to write down  $^{(2;2)}$ , we do not the matrix m  $_{\rm xy}^{(2;2)}$ , which is related to the matrix  $^{(2;2)}$  with

$$^{(2;2)} = m^{(2;2)} (^{(2;1)})^{-1}$$
: (65)

The matrix m (2;2) is given by

$$m_{in}^{(aa)(2;2)} = U(1 + i) + A_{00}^{(aa)(2;1)}$$

$$A_{i in} + A_{in}^{(aa)}C_{in}^{(aa)}$$

$$+ h(i)^{3}i_{in}: (66)$$

$$m_{ij}^{(ab)(2;2)} = p_{j}h(T_{i} T_{j})_{j} i p_{j}hT_{i} (_{i} _{j})i$$

$$X_{p_{ij}h(_{i} 1)_{j}}$$

$$(_{b}_{j1} + _{j}_{j1})_{1})i$$

$$X_{p_{nj}h(_{n} _{j})_{n}}$$

$$(_{i}_{in} + _{in}^{A})_{i}i$$

$$(67)$$

In these equations, we have introduced the following quantities;

$$T_{i}^{r} \quad \mathring{U}J_{i}^{r} + \mathring{V}_{ij}(J_{j}^{r} + J_{j}^{r});$$

$$J_{x}^{r} \quad {}_{xy}^{r}(d_{x}^{y} d_{y} d_{y} d_{x})$$

$$(68a)$$

$$\begin{array}{cccc}
p_{xy} (a_x^y & {}_{yz}^B b_z & {}_{yz}^B b_z^y & a_x \\
+ b_y^y & {}_{xz}^A a_z & {}_{xz}^A a_z^y & b_y );
\end{array}$$
(68b)

$$^{r}$$
 hT $_{\!x}$   $_{x}$  (1 2 $n_{\!i}$ )i

$$C_{xy}^{r}$$
  $h_{x}^{V}$   $y^{V}$   $i+U^{2}h_{4}^{1}$   $y^{r}$   $y^{r}$ 

Here, the label Y(r)' indicates either A (B)' or B (A)', whereas takes sign if the index x in the left hand side is in the A' lattice, and + if x is in the B' lattice. G reek indices; represent both site and spin indices. From eq. (65) m (bb) is also obtained by replacing a (A) with b(B) and p with p. The matrix m (ba) is obtained by the symmetry relationship  $m_{ji}^{(ba)} = m_{ij}^{(ab)}$ . By using these quantities, the remaining operator  $L_i$  in eq.(59) is expressed

as

$$L_{i} = T_{i} a_{i} + \sum_{i}^{A} A_{in} a_{n} \qquad p_{ij} (T_{i} T_{j}) b_{j} + L_{i}^{0} \qquad A_{in}^{A} f_{n}; \qquad (69)$$

where  $^{A}$  is de ned as  $^{A}$  in  $^{B}$   $^{A}$   $^{A}$   $^{A}$   $^{B}$   $^{A}$   $^{A}$ 

$$L_{i}^{0} = Q_{i} a_{i}$$
  $p_{ij}(Q_{i} Q_{j})b_{j}$ : (70)

Here, Q is defined as  $Q_i$  (  $_i$ )<sup>2</sup>  $\frac{h(_i)^3i}{h(_i)^2i}$  as the same as in the previous subsection. We ignore them in the same manner as in the previous subsection. The operator R  $_j$  is also written in the same way as

$$R_{j} = T_{j} b_{j} + \int_{j}^{x} \int_{jm}^{B} b_{m}$$
  $X_{ji} (T_{i} T_{j}) a_{i} + R_{j}^{0}$   $X_{jm}^{B} g_{m} :$  (71)

Here,  $R_{j}^{0}$  is given as

$$R_{j}^{0} = Q_{j} b_{j}$$
  $p_{ji}(Q_{i} Q_{j})a_{i};$  (72)

and it is neglected here.

This form ulation is valid only if the CDW order parameter is large enough to ignore the higher order of the expansion parameter p  $\frac{t}{2-cDW}$ . However, we expect that this form ulation gives better result even when the order parameter amplitude is modest since the CDW basis becomes correct in the strong coupling limit up to the second order in  $\frac{t}{V}$ . If the intersite interaction is large so that t  $\frac{t}{CDW}$ , one can expand the quasiparticle dispersion eq.(39) up to the second order in  $\frac{t}{CDW}$  as

$$k = {}_{CDW} + \frac{t_k^2}{2}$$
:

Perform ing Fourier transform ation, one can obtain the e ective hopping as

$$_{i;j} = \frac{t^2}{2_{CDW}} \quad _{i;j}$$

where  $_{i;j}$   $\frac{1}{N}^P$   $_k$   $e^{ik\;(r_i\;r_j)}$   $(2\;(\cos(k_x)+\cos(k_y))^2$  is the next-nearest neighbor hopping. This corresponds to the second order perturbation around the charge-ordered state. We refer to this formulation as CDW basis approach' in contrast to the formulation introduced in the previous subsection 'standard approach', which takes  $fc_i$  g as the operator basis.

# 3. Numerical Results

In this section, we show the result of the numerical calculations.

The following calculations have been performed on the 32 32 lattice with M atsubara frequencies 2048. The spectral functions have been obtained by analitic continuation using P ade approximation. <sup>34)</sup> The obtained real frequency data are smoothened by taking convolution

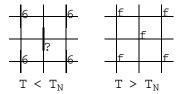


Fig. 1. Charge and/or spin distribution of the ordered patterns obtained by CPM (with CDW basis). Large circles indicate charge rich sites, while arrows indicate spin polarized sites. Left panel shows the solution for  $T < T_N$  with magnetic order. This pattern is the same as the HFA solution (3). Right panel shows the solution for  $T > T_N$  without magnetic order.

with the Gaussian distribution function N (!; )  $\frac{1}{2} e^{\frac{!^2}{2}}$  with = 0:05.

Through this paper the energy unit is set as t=1. First, we show the phase diagram of the extended H ubbard model obtained by CPM. We rst derived the charge-ordering transition line by the 'standard approach', taking  $c_i$  as the operator basis. We then have changed the basis to the 'CDW basis' in order to further analyze the region where the CDW order parameter  $c_{CDW}$  is large.

First, we compare the phase diagram obtained by CPM with the corresponding one obtained by the Hartree-Fock approximation (HFA). Here, the both calculations were performed allowing 2 2 sublattices. In the HFA calculation, we have examined longer-ranged ordering patterns allowing up to 4 4 sublattices but no other type of order was obtained as a stable phase. One clear dierence of the present CPM result from the corresponding result by HFA is seen in the existence of the insulating phase with charge order but without the magnetic order (non-magnetic insulating phase). Here we note that, even in the CPM calculation, antiferrormagnetic order is indeed obtained at low temperatures. The obtained ordering pattern is shown in Fig. 1, which is in agreement with strong-coupling analysis as well as the phase (3) of the HFA phase diagram. At rest thought, by taking account the fact we are considering two-dimensional system, we can argue that this result violates Mem in-Wagner theorem. This violation is, however, attributed to the mean-eld like nature of the calculation method. We can expect that the problem would be reduced if we take larger sublattices.

Here, we emphasize that in the CPM calculation, magnetic order is suppressed to low temperatures. In Fig 3 we have shown the Neel temperature for several parameters. This low ordering temperatures indicate that the magnetic order is induced by a small energy scale  $J_{\rm e}$ , which is the exchange energy in the charge-ordered phase. The explicit calculation of this energy will be given in the Appendix B. Here, the calculated  $T_{\rm N}$  is almost the same order as the exchange energy scale obtained by the strong coupling expansion. Although  $T_{\rm N}$  is higher than  $J_{\rm e}$  especially in the weak coupling region, this is attributed to the deviation from strong coupling assumption. On the other hand, metal-insulator transition as well as charge-ordering

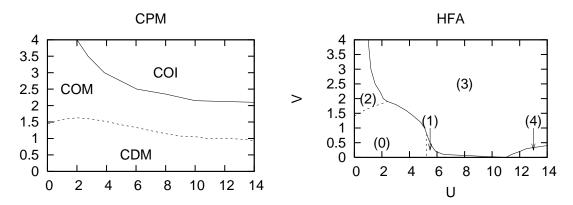


Fig. 2. Phase diagram for the extended Hubbard model at quarter lling. The left panel shows the result obtained by CPM, while the right panel shows the corresponding result obtained by HFA. Tem perature is set T = 0:15. The dotted lines indicate continuous transitions, while the solid lines indicate discontinuous transitions. In the left panel, COI, COM, and CDM indicate the charge-ordered insulating, the charge-ordered metallic, and the charge-disordered metallic phases, respectively. In the right panel, the labels (0) to (4) indicate dierent ordering patterns of spin and/or charge obtained by the HFA calculation. Each ordering pattern is shown in Appendix B.

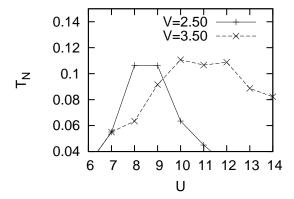


Fig. 3. Plot of the Neel tem perature  $T_N$  as a function of interaction parameter U , V . The result is obtained by CPM based on CDW basis.

transition occur in larger energy scale. We have con m ed that the charge order as well as the m etal-insulator transition up to T 0.5, which is several factor higher than  $T_N$ . This is in contrast to HFA, in which m agnetic long-range order is necessary to reduce double occupancy. Thus m agnetic order is induced by larger energy scale U, and it exists even in relatively high tem perature.

Using CPM (CDW basis approach) and taking account of short-range correlation e ects, we can obtain a phase with small double occupancy but without magnetic long-range order. This correspond to the non-magnetic insulating phase. Using HFA, the square lattice system at quarter lling become insulating only if there is a spin symmetry breaking which splits the

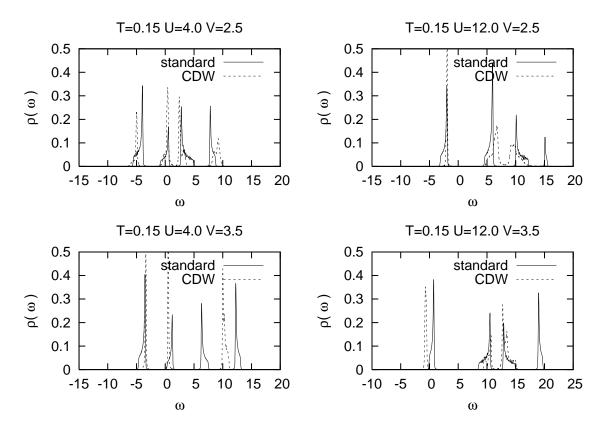


Fig. 4. Local density of states (!) of the extended Hubbard model at quarter lling. Tem perature is set T = 0.15, while the interaction parameters are set V = 2.5, U = 4.0;12.0, and V = 3.5, U = 4.0;12.0 respectively. Solid line indicates the result obtained by the CPM based on standard basis, while the dotted line indicates the result obtained by the CPM based on CDW basis.

band into four. On the other hand, by taking account of dynam ical correlation e ects as in CPM, one can reproduce insulating phase without magnetic symmetry breaking.

We note that application of CPM in the 'standard approach' does not reproduce the metalinsulator transition. This is because the operator projection analysis up to the second-order expansion cannot fully reproduce the correct dynamics around the charge-ordering transition. On the other hand, the formulation based on the CDW basis reproduces the metal-insulator transition. This is attributed to the fact that this formulation recovers the strong coupling limit up to the second order in  $\frac{t}{V}$  as we have seen before. This basis function gives qualitatively correct results even at the truncation up to the second order.

Here, one should note that the two approaches do not contradict at intermediate coupling since they are connected with (approximate) unitary transformation. Therefore, one can interpolate these two approaches and can obtain qualitatively correct results in the whole parameter space. In Fig. 4, we have plotted the spectral function obtained by the both approaches. The two spectra show similar structure for intermediate amplitude of V.

In Fig. 5, we show the spectral function of the metallic as well as the insulating phase.

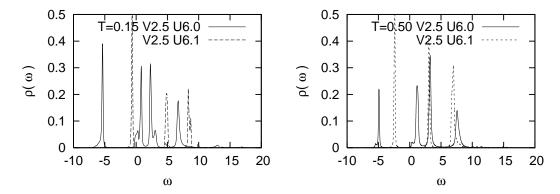


Fig. 5. Local density of states (!) at the metal-insulator transition point, The result is obtained by CPM based on CDW basis. Left panel shows the result for T=0.15. The parameter is set as  $V=2.5\ T=0.15$ , and U=6.0, U=6.1 respectively. The solid line indicates the metallic solution while the dotted line indicates the insulating solution. The right panel shows the result for T=0.50.

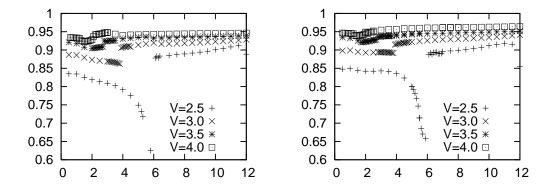


Fig. 6. O rder parameter of the charge-ordered phase h niplotted as a function of on-site interaction U.Tem perature is set T = 0.15 (left panel) and T = 0.50 (right panel), respectively.

The form er phase has a large density of states at the Ferm i level, while the latter phase has small density of states, which becomes vanishing in the zero temperature limit.

Our result shows that the transition is of the rst order, which is typical to (nite tem perature) metal-insulator transitions. The order parameter of the CDW state h ni h  $_{\rm A}$  i h  $_{\rm B}$  i jumps at the transition point as is shown Fig. 6

At xed V, the order parameter h ni decreases as a function of U in the metallic phase, but it takes nearly a constant value in the insulating phase. This is explained as follows; in the metallic phase with delocalized wave function, charge disproportionation increase the double occupancy and thus is disfavored in terms of the onsite repulsion term. On the other hand, in the insulating phase where the charges are localized each per one site, charge disproportionation does not severely increase the double occupancy. Moreover, suppression of the charge uctuations results in larger charge disproportionation in the insulating phase.

In this picture, however, the insulating phase occur only in the charge-ordered phase. This means that there exist charge-ordered metallic phase for a certain parameter region. On the other hand, such phases are not widely observed in experiments. This issue will be discussed in the next section.

# 4. Com parison to experim ental observations

In this section, we compare the obtained results with the experimental observations.

As we have mentioned in Sec.1, charge ordering occurs in various types of strongly correlated electron systems. Among them, charge ordering induced by the intersite Coulomb interactions is considered to be realized in a certain class of organic conductors. Here, we note that there are number of transition metal oxides (TMO) that shows charge ordering. There are, however, some diculties in comparing those materials with this result since in many cases, TMO's have more than one band and the spin degree of freedom is strongly coupled to the orbital degree of freedom. The result obtained here, by simple one band model with only electron-electron repulsion, may not be applicable. On the other hand, many of organic conductors have single conduction band and the result of single-band model is directly applicable. In addition to this, these materials provide good examples where the charge ordering temperature is much higher than the temperature at which spin degree of freedom is lost (magnetic-ordering temperature, spin Peierls temperature etc.) as we will see below.

For example,  $-(BEDT-TTF)_2MM^0(SCN)_4(M=Rb,Cs,M^0=Zn,Co)$  have large two-dimensional anisotropy and strong electron-electron correlations compared to the bandwidth. In addition to this, they have weak dimerization and regarded as quarter (hole-) lling system. Thus they o er good candidates of the charge-ordering system. In fact,

(BEDT-TTF)RbZn (SCN)4, for example, undergoes MIT at  $T_{MIT}=195K$  at ambient pressure, where the electrical resistivity shows sharp increase, with no sharp change in the magnetic susceptibility until a magnetic transition to spin Peierls state at  $T_{SP}=50K$ . <sup>5)</sup> The evidence of charge disproportionation was reported from the data of <sup>13</sup>C NMR shift and relaxation time measurement. <sup>14)</sup> Between 195K and 50K, an insulating phase without any magnetic order is observed, which is in agreement with our numerical calculation. The dynamical as well as spatial correlations are considered to be important in the above-mentioned system. The remaining magnetic degrees of freedom is lost through the spin-Peierls transition in the low temperature phase. This transition is considered to be induced by the coupling to the lattice degrees of freedom. Here, however, we do not further discuss this problem since we do not take account of lattice degrees of freedom. In this paper, we have adopted purely electronic model in order to study the physics in charge degrees of freedom. Study of the electron-lattice interplay remains as a future work.

Here, it should be noted that the ordering pattern observed in (BEDT-

 $TTF)_2RbZn$  (SCN) $_4$  is not the checkerboard order but of the stripe order. This di erence, however, m ay be attributed to the di erence of the lattice shape. In the real system, there exist nite values of the C oulomb interactions as well as the hopping in the diagonal directions.

More important di erence is the existence of the charge-ordered metallic phase in the numerical calculations, while it is not widely observed in experiments. This issue has been pointed out in Sec.1.0 ne possible reason for the di erence is the overestimate of the charge-ordered phase in the numerical calculation. Although CPM takes into account spatial short-ranged correlation elects, it still has a mean-eld like character. This may result in the underestimate of spatial uctuations and overestimate of charge order. If one could treat the spatial uctuations more accurately, the phase boundary between the charge-ordered phase and charge-disordered phase may merge to the phase boundary between the metallic and insulating phase. On the other hand, however, this problem might also be attributed to the limitation of the extended Hubbard model itself as a realistic model of real materials. In real materials, charge ordering often accompanies some additional symmetry breaking such as lattice distortion or dimerization, which may further stabilize the insulating phase.

#### 5. Sum mary

We have investigated the two-dimensional extended Hubbard model with the correlator projection method (CPM). CPM is a newly developed method which can treat correlation e ects in a self-consistent manner.

Applying CPM, we have shown that a metal-insulator transition is induced by charge ordering. The insulating phase has antiferrom agnetic order below  $T_{\rm N}$ , which is as the same order as the exchange interaction energy  $J_{\rm e}$ , but is non-magnetic insulator above  $T_{\rm N}$ . This is consistent with the strong-coupling picture as well as several experimental observations. The temperature scale of  $T_{\rm N}$  is several factor smaller than the charge-ordering temperature  $T_{\rm CO}$  and/or metal-insulator transition temperature  $T_{\rm M~IT}$ . We also emphasize that the obtained result is in contrast to the Hartree-Fock approximation. The dierence of energy scale as well as the existence of non-magnetic insulating phase is obtained by taking account of the dynamical and spatial correlation elects.

However, we have also obtained a charge-ordered m etallic phase that is not widely observed in realm aterials. The dierence may arise from the insu cient treatment of spatial uctuation elects. More accurate estimate of short-ranged spatial uctuation elects is left for future studies. The emergence of charge-ordered metal in the present result in general contradiction to the experimental observations may also be attributed to the limitation of the extended Hubbard model itself, where the coupling to lattice is ignored.

Although we clearly need further improvement, we have succeeded in obtaining a new formulation that can treat metal-insulator transitions induced by the charge ordering. The result also indicates that the qualitative aspect of the experimentally-observed metal-insulator

transitions in charge-ordering systems can be reproduced by a simple model as the extended Hubbard model if one carefully treat the correlation elects.

## 6. A cknow ledgem ents

One of the authors (K.H.) would like to thank S.Onoda, S.W atanabe, and Y.Im ai for stimulating discussions.

Appendix A: Phases obtained by the H artree-Fock approxim ation

The pattern of the charge and/or spin obtained by the Hartree-Fock approximation is shown below. We have examined possible spatial pattern up to 4—4 period and obtained the following 5 phases as stable ones. We do not exclude the possibility of obtaining lower energy state by allowing spatial patterns with longer period than 4—4.

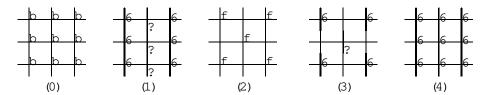


Fig. A 1. Charge and/or spin distribution of the ordered patterns obtained by HFA. Large circles indicate charge rich sites, while arrows indicate spin polarized sites. (0): no order (1):(;0) spin order (2):(;) charge order (3):(;) charge order with (;0) (0;) spin order (4): ferrom agnetic order

#### Appendix B: Derivation of exchange coupling parameter

The exchange interaction between localized charges in the checkerboard charge ordered state is derived from virtual processes shown in Fig. B 1. We do not the interaction strength parameter P m in (U; V). We not consider the strong coupling limit where P=t is in nitely large. Then we take account of the elect of nite value of hopping t by order by order in t=P. In Fig. B 1, the second order process (b) merely adds a constant energy shift irrespective of the spin con guration. Non-trivial elect comes from the fourth order perturbation. Contributions from this process dier depending on spin con gurations. In order to consider elective exchange interaction in the charge ordered phase, we introduce  $\frac{P}{2}$   $\frac{P}{2}$  meagnetic lattice. The elective interaction is then expressed in terms of the magnetic lattice as  $J_e$  in the nearest neighbor (n.n.) pairs and  $J_e^0$  in the next-nearest neighbor (n.n.) or the diagonal directions. Each is obtained as,

$$J_{e} = \frac{16t^{4}}{9V^{2}} \left( \frac{1}{U} + \frac{1}{4V + U} + \frac{1}{4V} \right);$$

$$J_{e}^{0} = \frac{4t^{4}}{9V^{2}} (\frac{1}{U} + \frac{2}{4V + U})$$

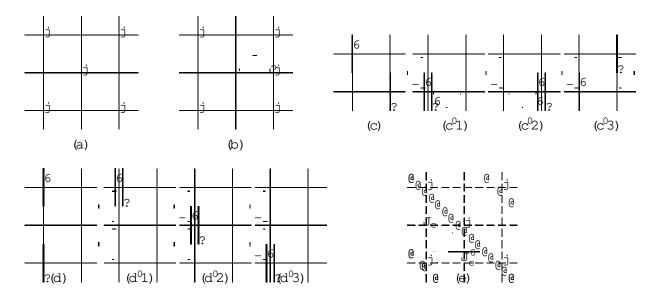


Fig. B 1. Virtual hopping processes up to the fourth order in t=P.C ircles indicate charges with no spin speci cation, while arrows indicate spin.(a) the ground state conguration in the strong coupling limit (zeroth order in t=P). (b) the second order perturbation process that gives uniform energy shift  $4\frac{t^2}{3V}$ . (c) spin pair of the second-nearest neighbor sites and (c01) to (c03) indicate dierent processes that contribute in the the fourth order perturbation. The contribution from each process is  $\frac{4t^4}{(3V)^2(4V+U)}$ ,  $\frac{4t^4}{(3V)^2U}$ , and  $\frac{4t^4}{(3V)^2(4V)}$ , respectively. (d) the spin pair of the third-neighbor sites and (d01) to (d03) indicate dierent processes that contribute in the the fourth order perturbation. The contribution from each process is  $\frac{t^4}{(3V)^2U}$ ,  $\frac{4t^4}{(3V)^2(4V+U)}$ , and  $\frac{t^4}{(3V)^2U}$ , respectively. (e) The elective  $\frac{p}{2}$   $\frac{p}{2}$  magnetic sublattices for the charge-ordered phase. The elective exchange is described as  $J_e$  and  $J_e^0$ .

respectively. Here, the e ective Ham iltonian has the form

$$H = J_e$$
  $S_i$   $S + J_e^0$   $S_i$   $S_i$   $S_i$   $S_i$   $S_i$   $S_i$ 

where S is the spin-1=2 operator at the charge-rich site of the charge-ordered phase, and P \_\_ < i;j>2nn. indicates the sum mation over all nearest neighbor pairs, while \_\_ < i;j>2nnn. indicates that of all next-nearest neighbor pairs (in the sense of  $\frac{p}{2}$   $\frac{p}{2}$  magnetic lattice).

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